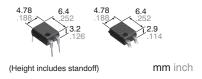


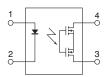


4-pin high capacity of 1.1A, I/O isolation voltage of 5,000V

Photo MOS GU 1 Form A High Capacity



CAD Data



FEATURES

- 1. Greatly increased capacity Continuous load current: 1.1A
- 2. Reinforced insulation I/O isolation voltage: 5,000 V AC
- 3. Compact 4-pin DIP type
- 4. The improved performance relative to mercury or mechanical relays

TYPICAL APPLICATIONS

- Measuring instruments
- · Security and disaster-preventing system: use in I/O for alarm and security devices, etc.

TYPES

	Output rating*			Part	Docking quantity			
			Through hole terminal		Surface-mount terminal		Packing quantity	
					Tape and ree	packing style	Tube	Tape and reel
	Load voltage	current	Tube packing style		Picked from the 1/2-pin side	Picked from the 3/4-pin side		
AC/DC dual use	60 V	1.1 A	AQY212GH	AQY212GHA	AQY212GHAX	AQY212GHAZ	1 tube contains 100 pcs. 1 batch contains 1,000 pcs.	1,000 pcs.

^{*}Indicate the peak AC and DC values.

Note: For space reasons, the three initial letters of the part number "AQY", the surface mount terminal shape indicator "A" and the packing style indicator "X" or "Z" are not marked on the relay.

RATING

1. Absolute maximum ratings (Ambient temperature: 25°C 77°F)

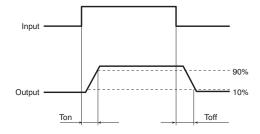
	Item	Symbol	AQY212GH(A)	Remarks
	LED forward current	le	50 mA	
lanut.	LED reverse voltage	VR	5 V	
Input	Peak forward current	IFP	1 A	f = 100 Hz, Duty factor = 0.1%
	Power dissipation	Pin	75 mW	
	Load voltage (peak AC)	VL	60 V	
Output	Continuous load current	IL.	1.1 A	Peak AC, DC
Output	Peak load current	Ipeak	3.0 A	100ms (1 shot), V _L = DC
	Power dissipation	Pout	500 mW	
Total power dissipation	on	Рт	550 mW	
I/O isolation voltage		Viso	5,000 V AC	
Tomporatura limita	Operating	Topr	-40°C to +85°C -40°F to +185°F	Non-condensing at low temperatures
Temperature limits	Storage	T _{stg}	-40°C to +100°C -40°F to +212°F	

GU 1 Form A High Capacity (AQY212GH)

2. Electrical characteristics (Ambient temperature: 25°C 77°F)

Item			Symbol	AQY212GH(A)	Condition	
Input	LED aparata gurrant	Typical	Fon	1.1 mA	I _L = 100mA	
	LED operate current	Maximum	IFon	3 mA		
	LED turn off current	Minimum	Foff	0.3 mA	IL = 100mA	
	LED tulli oli cullent	Typical	I Foff	1.0 mA	IL = TOOMA	
	LED dropout voltage	Typical	VF	1.32 V (1.14 V at I _F = 5 mA)	I _F = 50 mA	
	LED dropout voltage	Maximum	VF	1.5 V	IF = 30 IIIA	
	On resistance	Typical	Ron	0.34 Ω	I _F = 5 mA	
Output	On resistance	Maximum	Kon	0.7 Ω	Within 1 s on time	
	Off state leakage current	Maximum	I _{Leak}	1 μΑ	I _F = 0 mA V _L = Max.	
	Turn on time*	Typical	Ton	1.3 ms	I _F = 5 mA I _L = 100 mA	
	rum on time	Maximum		5.0 ms	VL = 10 V	
Transfer	T# #in *	Typical	_	0.1 ms	I _F = 5 mA	
characteristics	Turn off time*	Maximum	Toff	0.5 ms	IL = 100 mA VL = 10 V	
	1/0	Typical	m Ciso	0.8 pF	f = 1 MHz	
	I/O capacitance	Maximum		1.5 pF	V _B = 0 V	
	Initial I/O isolation resistance	Minimum	Riso	1,000 ΜΩ	500 V DC	

^{*}Turn on/Turn off time



RECOMMENDED OPERATING CONDITIONS

Please obey the following conditions to ensure proper relay operation and resetting.

	•	•		
•	Item	Symbol	Recommended value	Unit
•	Input LED current	lf	5 to 10	mA

- **Dimensions**
- Schematic and Wiring Diagrams
- Cautions for Use
- These products are not designed for automotive use.

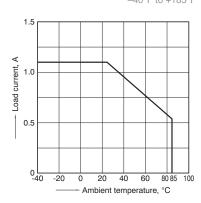
If you are considering to use these products for automotive applications, please contact your local Panasonic technical representative.

Please refer to our information on PhotoMOS Relays for Automotive Applications.

REFERENCE DATA

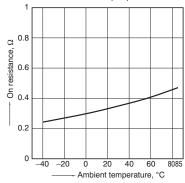
 Load current vs. ambient temperature characteristics

Allowable ambient temperature: -40°C to +85°C -40°F to +185°F



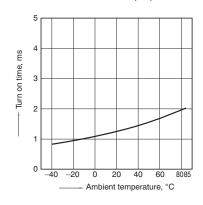
2. On resistance vs. ambient temperature characteristics

Measured portion: between terminals 3 and 4; LED current: 5 mA; Load voltage: Max. (DC) Continuous load current: Max.(DC)



Turn on time vs. ambient temperature characteristics

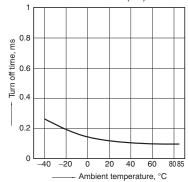
LED current: 5 mA; Load voltage: 10 V (DC); Continuous load current: 100 mA (DC)



GU 1 Form A High Capacity (AQY212GH)

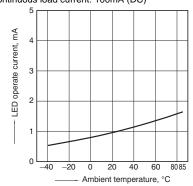
4. Turn off time vs. ambient temperature characteristics

LED current: 5 mA; Load voltage: 10 V (DC); Continuous load current: 100 mA (DC)

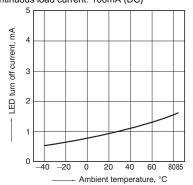


5. LED operate current vs. ambient temperature characteristics Load voltage: 10 V (DC);

Continuous load current: 100mA (DC)

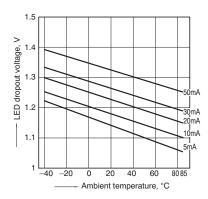


6. LED turn off current vs. ambient temperature characteristics Load voltage: 10 V (DC); Continuous load current: 100mA (DC)



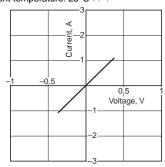
7. LED dropout voltage vs. ambient temperature characteristics

LED current: 5 to 50 mA



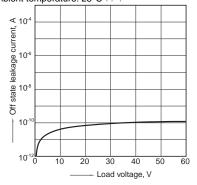
8. Current vs. voltage characteristics of output at MOS portion

Measured portion: between terminals 3 and 4; Ambient temperature: 25°C 77°F



9. Off state leakage current vs. load voltage characteristics

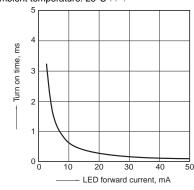
Measured portion: between terminals 3 and 4; Ambient temperature: 25°C 77°F



10. Turn on time vs. LED forward current characteristics

Measured portion: between terminals 3 and 4; Load voltage: 10 V (DC);

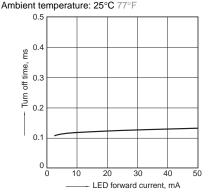
Continuous load current: 100 mA (DC); Ambient temperature: 25°C 77°F



11. Turn off time vs. LED forward current characteristics

Measured portion: between terminals 3 and 4; Load voltage: 10 V (DC);

Continuous load current: 100 mA (DC);



12. Output capacitance vs. applied voltage characteristics

Measured portion: between terminals 3 and 4;

Frequency: 1 MHz;

Ambient temperature: 25°C 77°F

